UNISONIC TECHNOLOGIES CO., LTD

UTG15N120-H

Preliminary

Insulated Gate Bipolar Transistor

1200V TRENCH GATE FIELD-STOP IGBT

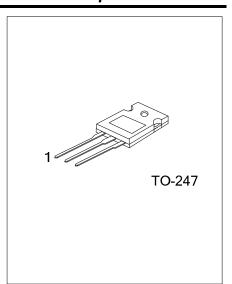
DESCRIPTION

The UTC **UTG15N120-H** is an Trench Field-Stop Insulated Gate Bipolar Transistor. it uses UTC's advanced technology to provide customers with high switching speed, low saturation voltage and low switching loss, etc.

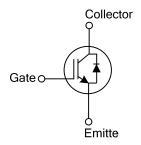
The UTC **UTG15N120-H** is suitable for the resonant or soft switching applications.

■ FEATURES

- * High switching speed
- * High avalanche ruggedness
- * Low saturation voltage: $V_{CE(SAT).Typ.}$ =1.85V @ I_C =15A, V_{GE} =15V (T_C =25°C)



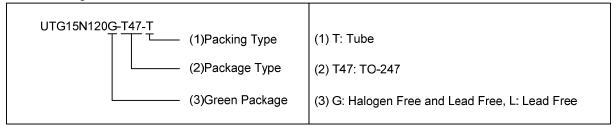
■ SYMBOL



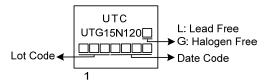
ORDERING INFORMATION

Ordering Number		Dealtage	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UTG15N120L-T47-T	UTG15N120G-T47-T	TO-247	G	С	E	Tube	

Note: Pin Assignment: G: Gate C: Collector E: Emitter



MARKING



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■ ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Emitter Voltage		V_{CES}	1200	V
Gate-Emitter Voltage		\/	±20	V
Transient Gate-emitter voltage (tp < 5 ms)		V _{GES}	±25	V
Continuous Collector Current	T _C =25°C		30	Α
	T _C =100°C	- I _C	15	Α
Collector Current Pulsed (Note 1)		I _{CM}	60	Α
Diode Forward Current	T _C =25°C		30	Α
	T _C =100°C	I _F	15	Α
Short Circuit Withstand Time $V_{GE} = 15V, V_{CC} \le 200V$				μs
Allowed number of short circuits < 1000		t _{sc}	10	
Time between short circuits: ≥1.0s				
T _{VJ} = 25°C				
Power Dissipation (T _C =25°C)		P_D	240	W
Operating Junction Temperature		T_J	-40 ~ +175	°C
Storage Temperature Range		T _{STG}	-55 ~ + 175	°C

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

■ THERMAL DATA

	PARAMETER	SYMBOL	RATING	UNIT
Jι	unction to Case	$\theta_{ m JC}$	0.52	°C/W

^{2.} Pulse width limited by maximum junction temperature.

■ ELECTRICAL CHARACTERISTICS (T_C=25°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT	
Off Characteristics								
Collector-Emitter Breakdown Voltage	BV _{CES}			1200			V	
Collector Cut-Off Current	I _{CES}	V _{CE} =1200V, V _{GE} =0V				5	μΑ	
G-E Leakage Current	I _{GES}	V _{CE} =0V, V _{GE} =±20V				±400	nA	
On Characteristics								
Gate to Emitter Threshold Voltage	$V_{GE(TH)}$	I _C =250μA, V _{CE} =V _{GE}		4.5		7.5	V	
Collector to Emitter Saturation Voltage		1 -450 \/ -45\/	T _C =25°C		1.85	2.3	V	
	$V_{CE(SAT)}$	I _C =15A, V _{GE} =15V	T _C =125°C		2.4		V	
Dynamic Characteristics								
Input Capacitance	C _{IES}				1830		pF	
Output Capacitance	C_OES	V _{CE} =25V, V _{GE} =0V, f=1		109		pF		
Reverse Transfer Capacitance	C _{RES}				47		pF	
Switching Characteristics								
Total Gate Charge	Q_{G}				139		nC	
Gate-Emitter Charge	Q_GE	V _{CE} =600V, I _C =15A, V _{GE} =15V			21		nC	
Gate-Collector Charge	Q_GC			88		nC		
Turn-On Delay Time	t _{DON)}	V _{CC} =600V, I _C =15A, R _G =5Ω, V _{GE} =0~15V, L=500uH			14.4		ns	
Rise Time	t _R				23.9		ns	
Turn-Off Delay Time	t _{DOFF)}				117.4		ns	
Fall Time	t⊧				212.6		ns	
Turn-On Switching Loss	Eon				0.896		mJ	
Turn-Off Switching Loss	E _{OFF}				0.903		mJ	
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS								
Forward Voltage Drop	V _F	I _F =15A				2.0	V	
Reverse Recovery Time	t _{rr}	I _F =15A, dI/dt=100A/μS, V _{CC} =600V			70.3		ns	
Reverse Recovery Charge	Qrr				2.68		μC	

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